

ZXTP19020CFF

20V, SOT23F, PNP medium power transistor

Summary:

$BV_{CEO} > -20V$

$BV_{ECO} > -5V$

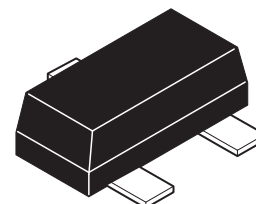
$I_{C(cont)} = -5A$

$V_{CE(sat)} < 40mV @ 100mA$

$R_{CE(sat)} = 21m\Omega$

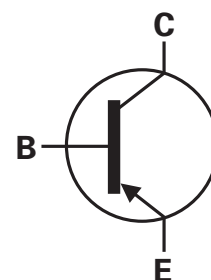
$P_D = 1.5W$

Complementary part number ZXTN19020CFF



Description

Advanced process capability has been used to maximize the performance of this transistor. The SOT23F package is compatible with the industry standard SOT23 footprint but offers lower profile and higher dissipation for applications where power density is of utmost importance.

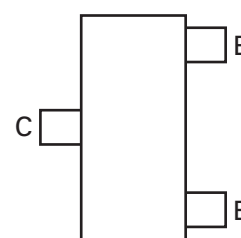


Features

- High gain
- Low saturation voltage
- Low profile high dissipation package

Applications

- Battery charging
- Load switch
- DC-DC converters



Pinout - top view

Ordering information

Device	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP19020CFFTA	7	8	3000

Device marking

1D7

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Absolute maximum ratings

Parameter	Symbol	Limit	Unit
Collector-base voltage	V_{CBO}	-25	V
Collector-emitter voltage	V_{CEO}	-20	V
Emitter-collector voltage (reverse blocking)	V_{ECO}	-5	V
Emitter-base voltage	V_{EBO}	-7	V
Continuous collector current ^(c)	I_C	-5	A
Peak pulse current	I_{CM}	-10	A
Base current	I_B	-1	A
Power dissipation at $T_{amb} = 25^{\circ}C^{(a)}$	P_D	0.84	W
Linear derating factor		6.72	mW/ $^{\circ}C$
Power dissipation at $T_{amb} = 25^{\circ}C^{(b)}$	P_D	1.34	W
Linear derating factor		10.72	mW/ $^{\circ}C$
Power dissipation at $T_{amb} = 25^{\circ}C^{(c)}$	P_D	1.5	W
Linear derating factor		12.0	mW/ $^{\circ}C$
Power dissipation at $T_{amb} = 25^{\circ}C^{(d)}$	P_D	2.0	W
Linear derating factor		16.0	mW/ $^{\circ}C$
Operating and storage temperature range	T_J, T_{stg}	-55 to 150	$^{\circ}C$
Thermal resistance			
Parameter	Symbol	Value	Unit
Junction to ambient ^(a)	$R_{\theta JA}$	149.3	$^{\circ}C/W$
Junction to ambient ^(b)	$R_{\theta JA}$	93.4	$^{\circ}C/W$
Junction to ambient ^(c)	$R_{\theta JA}$	83.3	$^{\circ}C/W$
Junction to ambient ^(d)	$R_{\theta JA}$	60	$^{\circ}C/W$

NOTES:

(a) For a device surface mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

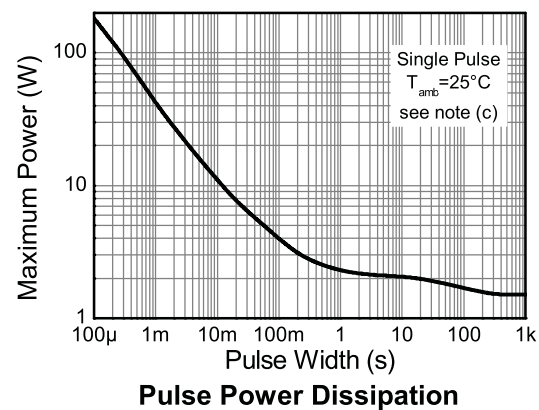
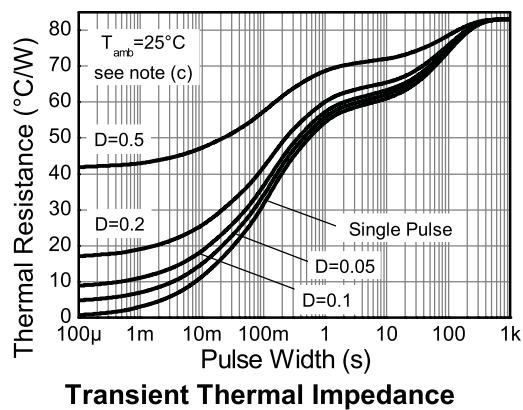
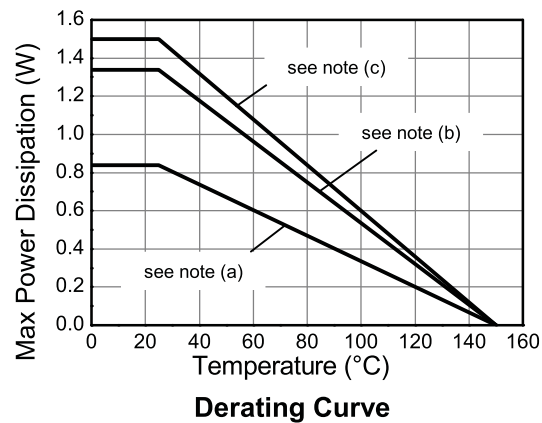
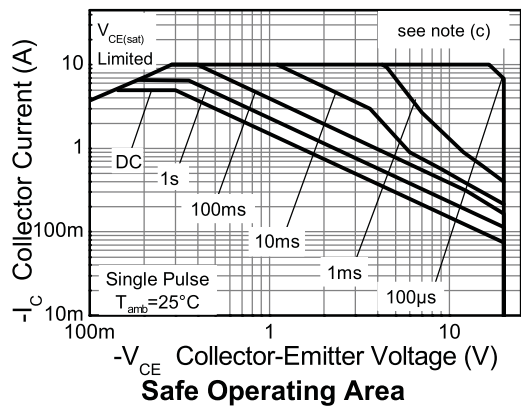
(b) Mounted on 25mm x 25mm x 1.6mm FR4 PCB with a high coverage of single sided 2 oz copper in still air conditions.

(c) Mounted on 50mm x 50mm x 1.6mm FR4 PCB with a high coverage of single sided 2 oz copper in still air conditions.

(d) As (c) above measured at $t < 5$ secs.

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Characteristics



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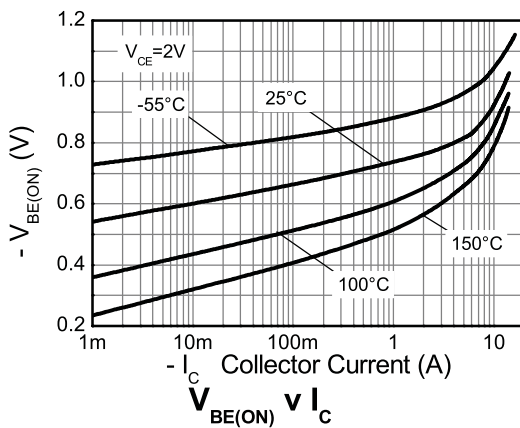
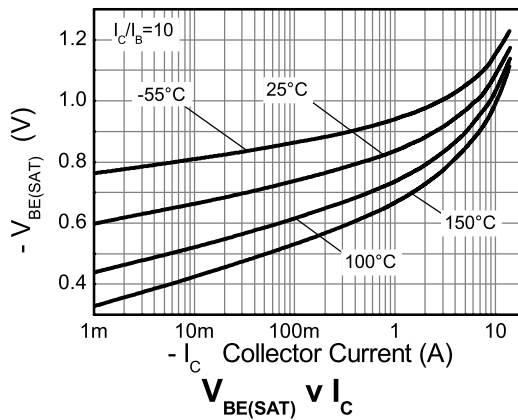
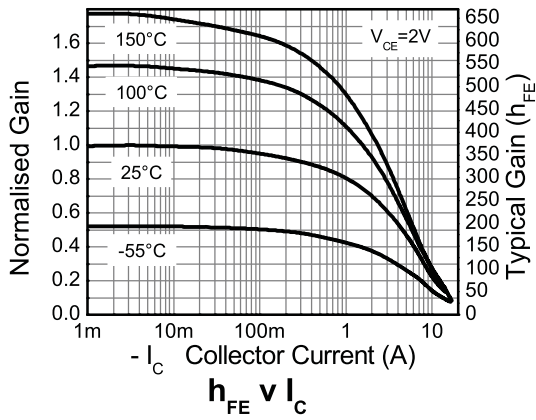
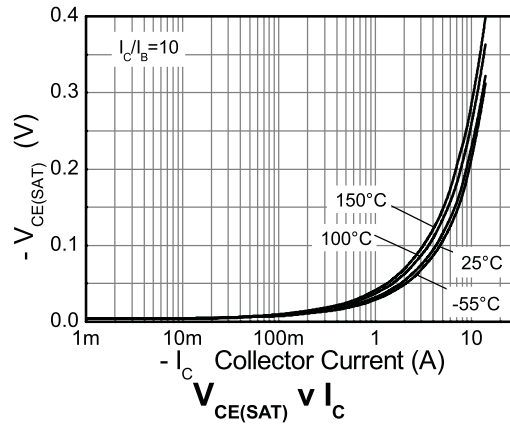
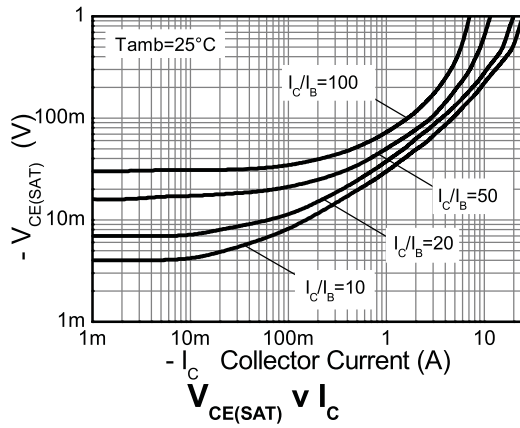
Electrical characteristics (at $T_{amb} = 25^{\circ}\text{C}$ unless otherwise stated)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV_{CBO}	-25	-45		V	$I_C = -100\mu\text{A}$
Collector-emitter breakdown voltage (base open)	BV_{CEO}	-20	-30		V	$I_C = -10\text{mA}^{(*)}$
Emitter-base breakdown voltage	BV_{EBO}	-7	-8.3		V	$I_E = -100\mu\text{A}$
Emitter-collector breakdown voltage (reverse blocking)	BV_{ECX}	-6	-8.3		V	$I_E = -100\mu\text{A}$, $R_{BC} \leq 1\text{k}\Omega$ or $0.25\text{V} < V_{BC} < -0.25\text{V}$
Emitter-collector breakdown voltage (base open)	BV_{ECO}	-5	-8.5		V	$I_E = -100\mu\text{A}$,
Collector-base cut-off current	I_{CBO}		< -1	-50 -20	nA μA	$V_{CB} = -20\text{V}$ $V_{CB} = -20\text{V}$, $T_{amb} = 100^{\circ}\text{C}$
Emitter-base cut-off current	I_{EBO}		< -1	-50	nA	$V_{EB} = -5.6\text{V}$
Collector-emitter saturation voltage	$V_{CE(sat)}$		-30 -50 -75 -105	-40 -70 -120 -135	mV mV mV mV	$I_C = -1\text{A}$, $I_B = -100\text{mA}^{(*)}$ $I_C = -1\text{A}$, $I_B = -20\text{mA}^{(*)}$ $I_C = -2\text{A}$, $I_B = -40\text{mA}^{(*)}$ $I_C = -5\text{A}$, $I_B = -500\text{mA}^{(*)}$
Base-emitter saturation voltage	$V_{BE(sat)}$		-925	-1050	mV	$I_C = -5\text{A}$, $I_B = -500\text{mA}^{(*)}$
Base-emitter turn-on voltage	$V_{BE(on)}$		-815	-950	mV	$I_C = -5\text{A}$, $V_{CE} = -2\text{V}^{(*)}$
Static forward current transfer ratio	h_{FE}	200 170 110	350 300 180	500		$I_C = -100\text{mA}$, $V_{CE} = -2\text{V}^{(*)}$ $I_C = -1\text{A}$, $V_{CE} = -2\text{V}^{(*)}$ $I_C = -5\text{A}$, $V_{CE} = -2\text{V}^{(*)}$
Transition frequency	f_T		200		MHz	$I_C = -50\text{mA}$, $V_{CE} = -10\text{V}$ $f = 100\text{MHz}$
Output capacitance	C_{obo}		52	70	pF	$V_{CB} = -10\text{V}$, $f = 1\text{MHz}^{(*)}$
Delay time	t_d		66.8		ns	$V_{CC} = -15\text{V}$. $I_C = -750\text{mA}$, $I_{B1} = 15\text{mA}$, $I_{B2} = -15\text{mA}$.
Rise time	t_r		74.9		ns	
Storage time	t_s		226		ns	
Fall time	t_f		85.5		ns	

NOTES:

(*) Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$; duty cycle $\leq 2\%$.

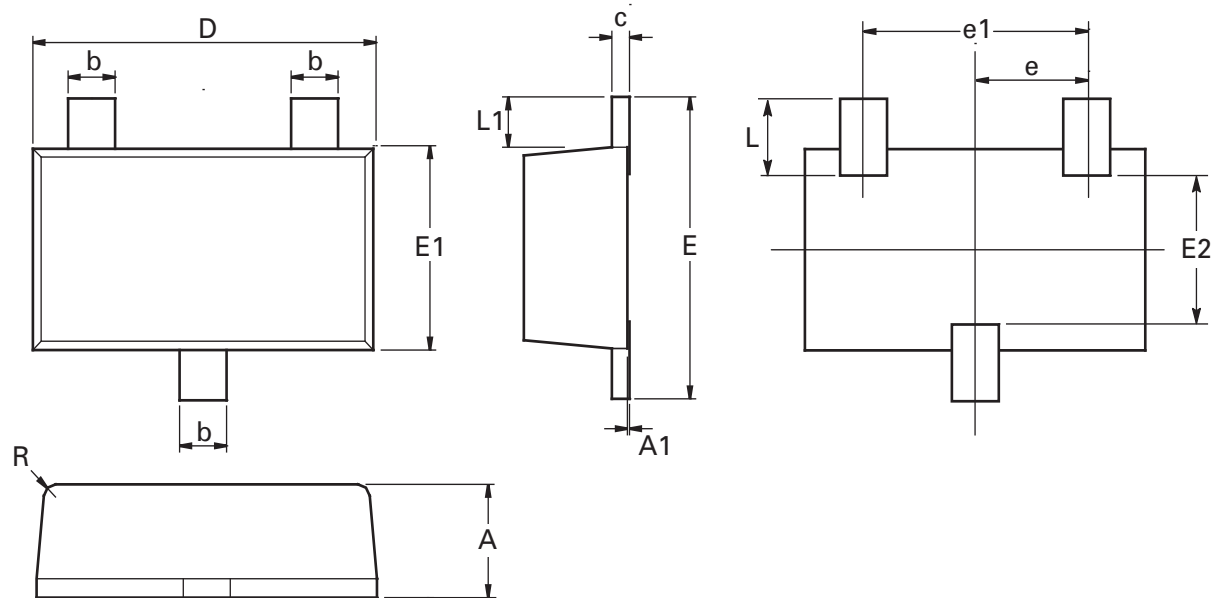
Typical characteristics



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Package outline - SOT23F



Dim.	Millimeters		Inches		Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Max.	Max.
A	0.80	1.00	0.0315	0.0394	E	2.30	2.50	0.0906	0.0984
A1	0.00	0.10	0.00	0.0043	E1	1.50	1.70	0.0590	0.0669
b	0.35	0.45	0.0153	0.0161	E2	1.10	1.26	0.0433	0.0496
c	0.10	0.20	0.0043	0.0079	L	0.48	0.68	0.0189	0.0268
D	2.80	3.00	0.1102	0.1181	L1	0.30	0.50	0.0153	0.0161
e	0.95 ref		0.0374 ref		R	0.05	0.15	0.0019	0.0059
e1	1.80	2.00	0.0709	0.0787	O	0°	12°	0°	12°

Note: Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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